Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L23	46266	(high adj (k or dielectric)) or HfSiO or HfSiON or HfO2 or HfO?sub?2	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/15 19:47
L24	9862	23 and (anneal\$6 or RTA or heat\$6 or thermal or temperature) near20 (oxidizing or H2O or H2O2 or H?sub?2O or H?sub?2O or oxidat\$6 or oxygen)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/15 19:49
L25	7514	23 and ((anneal\$6 or RTA or heat\$6 or thermal or temperature) near20 (inert or N2 or nitrogen or N?sub?2 or Ar or argon or He or helium or Ne or neon))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/15 19:50
L26	42389	23 and (@ad<"20031211" or @rlad<"20031211")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/15 19:51
L27	15430	23 and (gate or transistor or FET or MOSFET or TFT)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/15 19:52
L28	2512	24 and 25 and 26 and 27	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/15 19:49
L29	2239	23 same (anneal\$6 or RTA or heat\$6 or thermal or temperature) near20 (oxidizing or H2O or H2O2 or H?sub?2O or H?sub?0?sub?2 or oxidat\$6 or oxygen)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/15 19:49
L30	759	23 same ((anneal\$6 or RTA or heat\$6 or thermal or temperature) near20 (inert or N2 or nitrogen or N?sub?2 or Ar or argon or He or helium or Ne or neon))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/15 19:50
L31	759	23 same ((anneal\$6 or RTA or heat\$6 or thermal or temperature) near20 (inert or N2 or nitrogen or N?sub?2 or Ar or argon or He or helium or Ne or neon))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/15 19:50

L32	237	23 same (nitridiz\$6 or nitrif\$6 or nitriding)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/15 19:51
L33	42	29 and 30 and 31 and 32	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/15 19:51
L34	31	33 and (@ad<"20031211" or @rlad<"20031211")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/15 19:51
L35	31	34 and (gate or transistor or FET or MOSFET or TFT)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/15 19:52